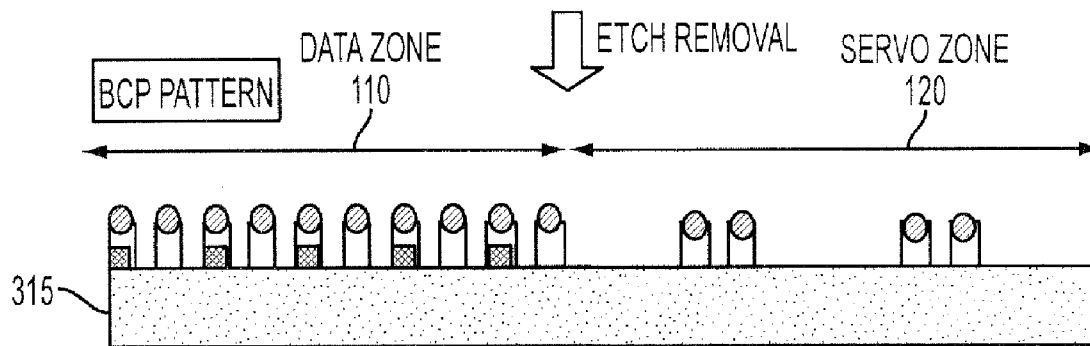




US 20120196094A1

(19) **United States**(12) **Patent Application Publication****Xu et al.**(10) **Pub. No.: US 2012/0196094 A1**(43) **Pub. Date: Aug. 2, 2012**(54) **HYBRID-GUIDED BLOCK COPOLYMER ASSEMBLY***B05D 3/06* (2006.01)*B05D 3/12* (2006.01)*B05D 3/00* (2006.01)*B05D 3/10* (2006.01)(75) Inventors: **Yuan Xu**, Fremont, CA (US); **Kim Lee**, Fremont, CA (US); **Wei Hu**, Chandler, AZ (US); **Koichi Wago**, Sunnyvale, CA (US); **David Shiao-Min Kuo**, Palo Alto, CA (US)(52) **U.S. Cl. 428/195.1; 427/299; 427/535; 427/553; 427/314; 427/256**(73) Assignee: **SEAGATE TECHNOLOGY LLC**, SCOTTS VALLEY, CA (US)(57) **ABSTRACT**(21) Appl. No.: **13/018,416**(22) Filed: **Jan. 31, 2011****Publication Classification**(51) **Int. Cl.***B32B 3/00* (2006.01)*B05D 1/36* (2006.01)

A method for nano-patterning includes imprinting features in a resist with an imprint mold to form one or more topographic surface patterns on the imprinted resist. A block copolymer ("BCP") material is deposited on the imprinted resist, wherein a molecular dimension L_0 of the BCP material correlates by an integer multiple to a spacing dimension of the one or more topographic surface patterns on the imprinted resist. The deposited BCP is annealed and at least a portion of the annealed BCP is removed, forming a template having discrete domains.



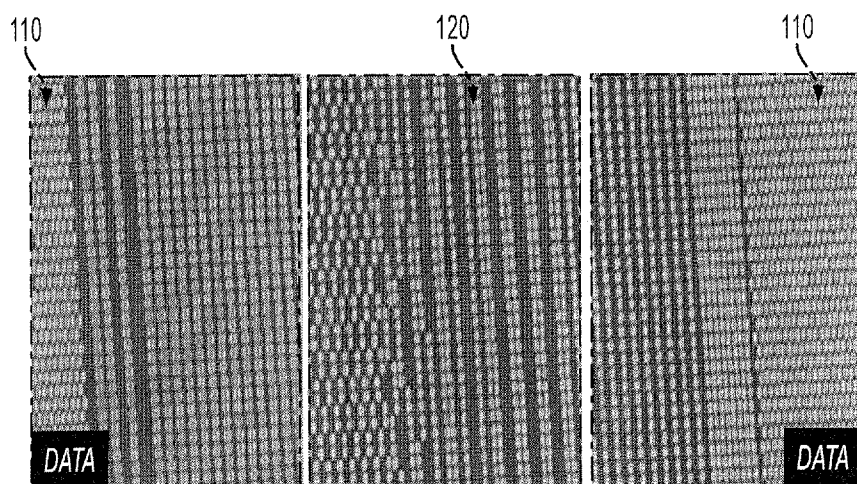
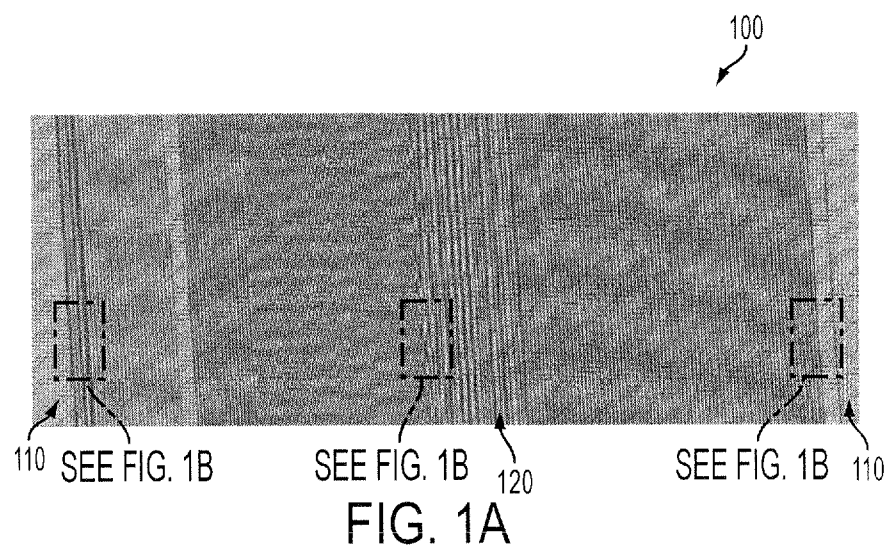


FIG. 1B

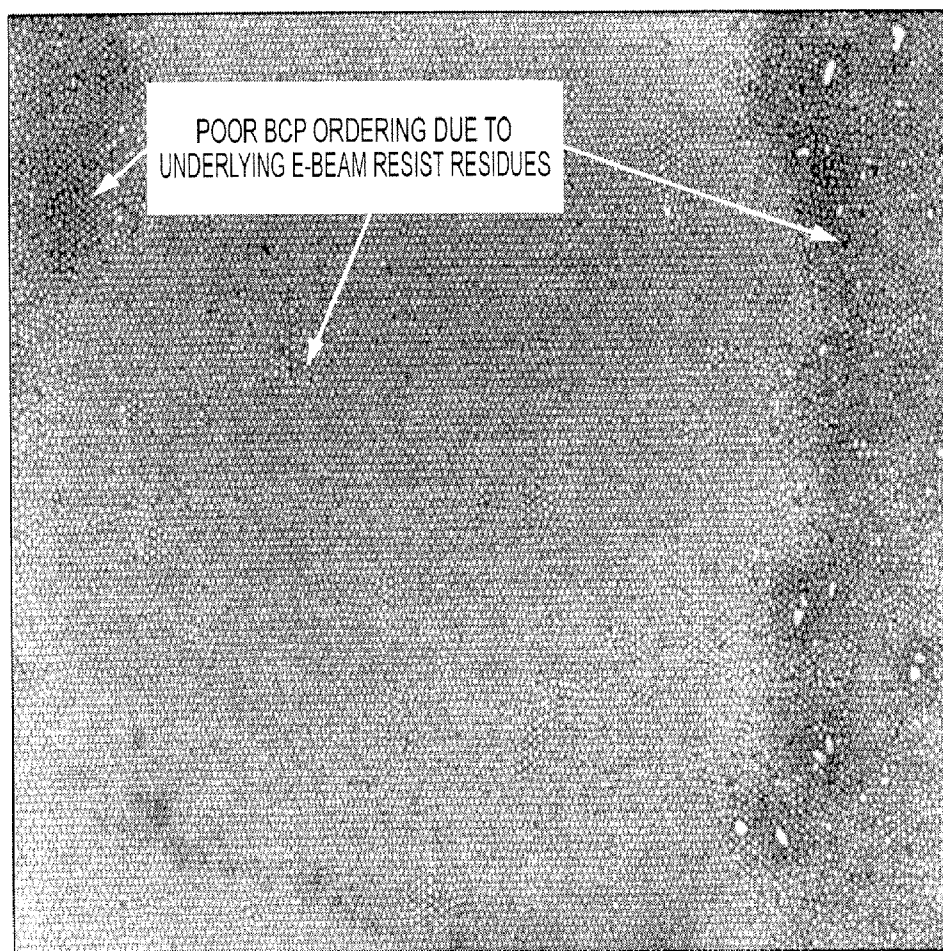


FIG. 2

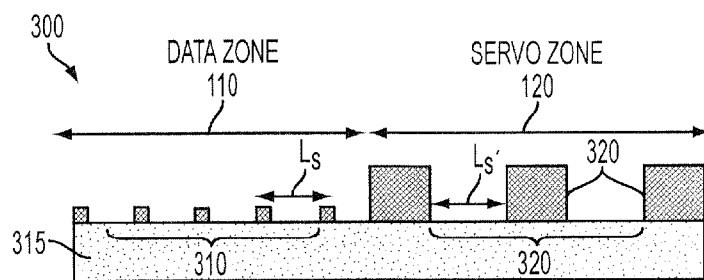


FIG. 3A

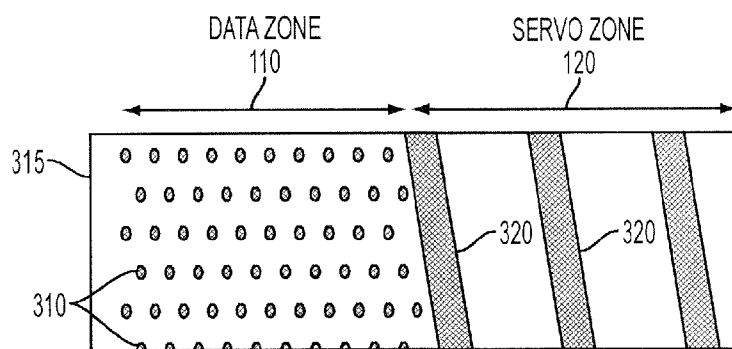


FIG. 3B

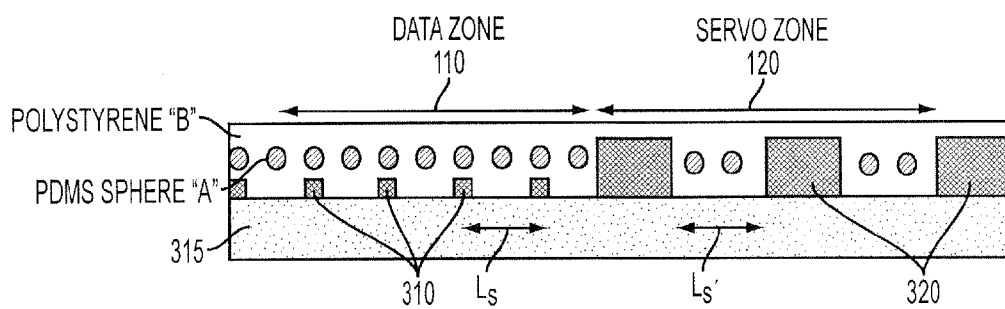


FIG. 3C

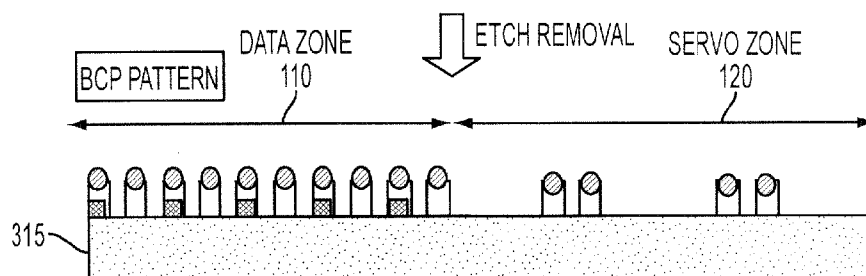


FIG. 3D

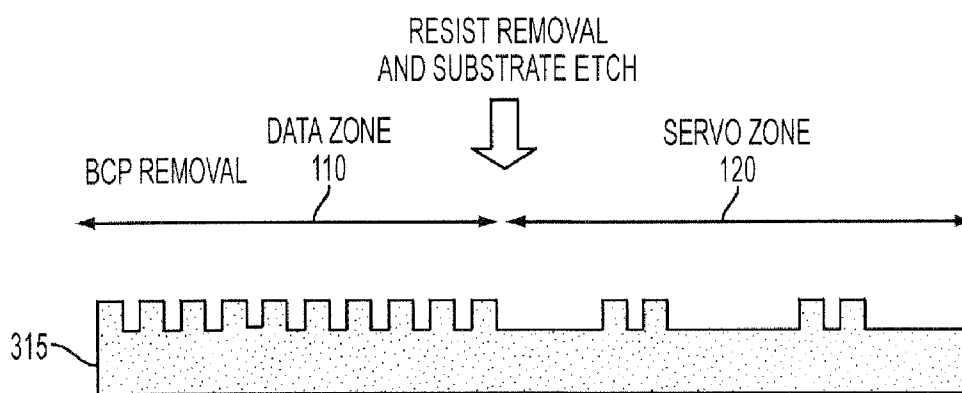


FIG. 3E

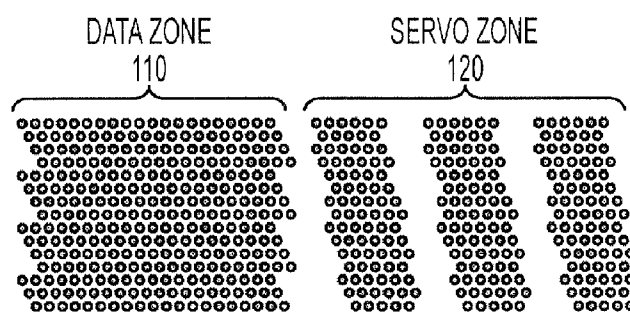


FIG. 3F

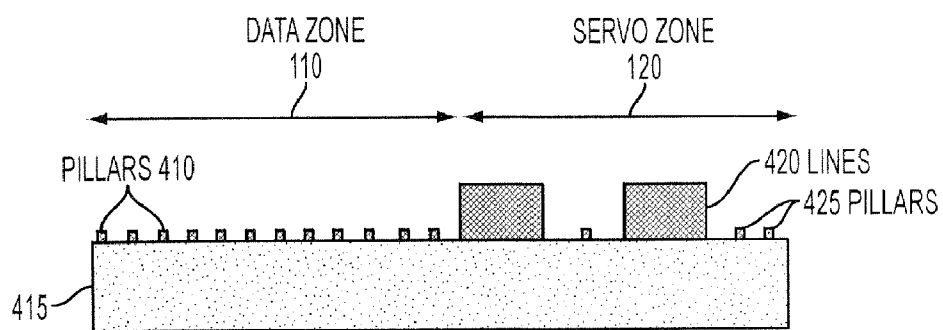


FIG. 4A

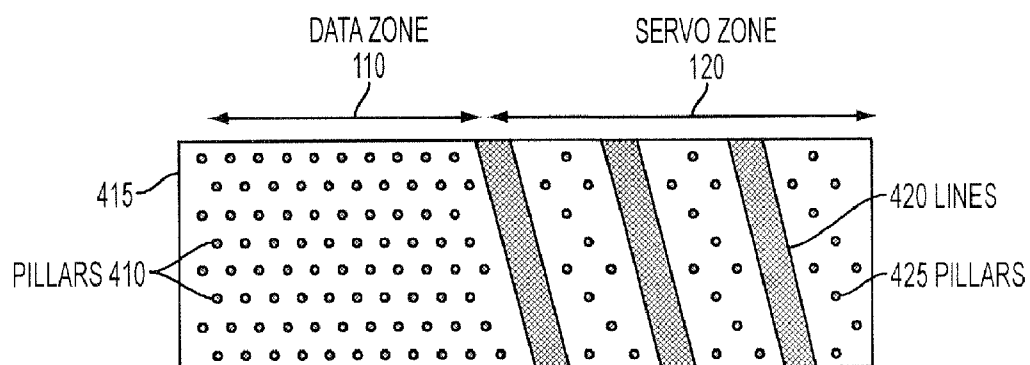


FIG. 4B

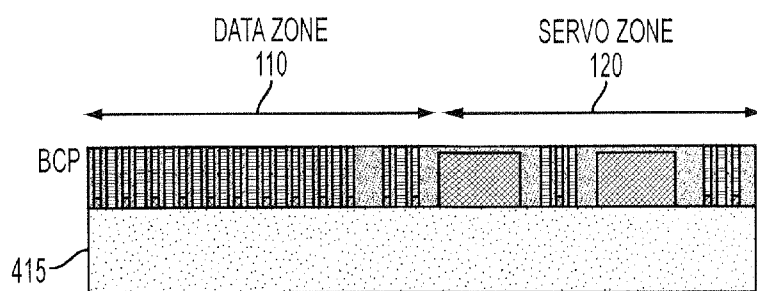


FIG. 4C

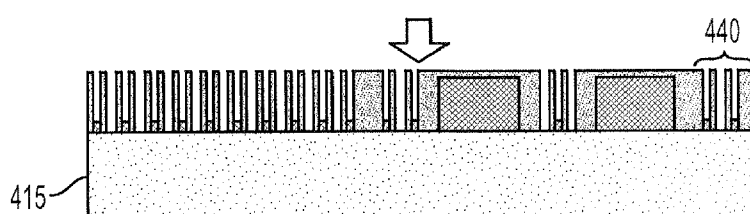


FIG. 4D

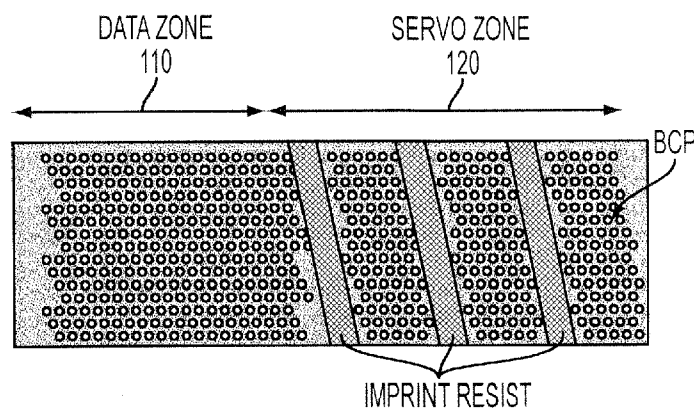


FIG. 4E

RESULTANT HIGH DENSITY TEMPLATE WITH SERVO

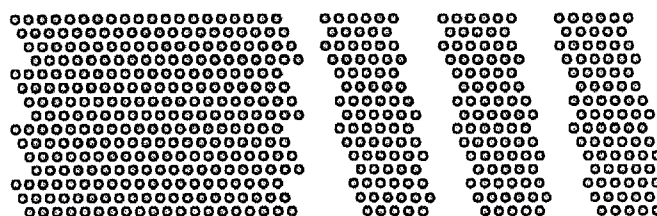


FIG. 4F

HYBRID-GUIDED BLOCK COPOLYMER ASSEMBLY

FIELD

[0001] This disclosure relates generally to the use of block copolymers for high density patterning.

BACKGROUND

[0002] Bit pattern media (BPM) has been extensively explored by the magnetic recording industry as one of several key solutions to expand perpendicular magnetic recording (PMR) technology in high density disk drives (HDDs). A typical BPM media consists of two repeating zones—a data zone and a servo zone. Data zones consist of homogenous dots to store data bits. Servo zones consist of dots with various patterns to describe a location and address of information in the data zone. In the servo zone, dots need be arranged into various pattern and spacings to encode information such as head position, timing, and tracking following information for a respective data zone.

[0003] The storage capacity of BPM is dependent upon the density of the magnetic islands, or “bits” on the media substrate surface. Current processes for achieving high density patterned media include imprint mold fabrication, nano-imprinting and pattern transfer into magnetic dots, and the like.

[0004] Self-assembling block copolymer (BCP) enables high-density lithographic bit patterning capability and is a promising material for BPM template fabrication. Directed self-assembly combines ‘top-down’ lithography (pre-registered pattern) and ‘bottom-up’ self-assembling materials like block copolymers. Directed self-assembly may generate ultra-high density homogenous patterns.

SUMMARY

[0005] In an embodiment, a method for nan-opatterning includes imprinting features in a resist on a substrate with an imprint mold to form one or more topographic surface patterns on the resulting imprinted resist. A block copolymer (“BCP”) material is deposited on the resulting imprinted resist, wherein a molecular dimension L_0 of the BCP material correlates by an integer multiple to a spacing dimension of the one or more topographic surface patterns on the resulting imprinted resist. The deposited BCP is annealed and at least a portion of the annealed BCP is removed, forming a template having discrete domains.

BRIEF DESCRIPTION OF THE FIGURES

[0006] Embodiments of this disclosure are illustrated by way of example and not limitation in the figures of the accompanying drawings, in which like references indicate similar elements, and in which:

[0007] FIG. 1A is an SEM image showing data zones and servo zones in bit patterned media in accordance with an embodiment.

[0008] FIG. 1B is an SEM image showing high resolution segments of the bit patterned media of FIG. 1A.

[0009] FIG. 2 is a scanning electron microscope (“SEM”) image of patterned media pre-patterned using e-beam lithography followed by a BCP patterning process, according to an embodiment.

[0010] FIGS. 3A-3F illustrates a hybrid pre-pattern structure for self-guided assembly of servo zone and data zone structures, according to an embodiment.

[0011] FIGS. 4A-4F illustrate another example for integrated template fabrication using hybrid guiding pre-pattern for BCP self-assembly with cylindrical block copolymer of servo zone and data zone structures, according to an embodiment.

DETAILED DESCRIPTION

[0012] A high density disk drive (HDD) 100 is a medium that has different regions besides the regions used for storing data (data zones 110). For example, as shown in FIGS. 1A and 1B, a bit pattern media HDD 100 includes the data zone 110 which consists of homogeneous dots to store data bits. In addition to a data zone 110, the HDD 110 may typically have a servo zone 120 used to describe the location and address information in the data zone 110. Various shapes and spacings may be formed in the servo zone 120 to encode information such as head position, timing, and track-following information for a respective data zone.

[0013] FIG. 2 is a scanning electron microscope (“SEM”) image of bit patterned media (BPM) pre-patterned using e-beam lithography followed by a BCP patterning process. As FIG. 2 illustrates, the long-range lateral ordering of the bits are compromised by contaminants left behind by the e-beam lithography. Moreover, the chemicals used in the e-beam lithography wet stripping process are typically hazardous to human health and are environmentally unsound.

[0014] Referring back to FIGS. 1A and 1B, disclosed herein is a method to fabricate a template for BPM with the servo zone 120 fabrication integrated with the data zone 110 fabrication of BPM by simultaneously forming both data format and servo format zones 110 and 120, respectively, via a hybrid-guided BCP self-assembly process. The method of applying hybrid guiding pre-patterning for BCP self-assembly disclosed here may provide both BCP long-range order for formation of the data zone 110 by utilizing pre-register dots to guide formation of data zone dots and simultaneous shape manipulation for formation of the servo zone 120 by utilizing ridge-groove guiding to form patterns of servo zone dots.

[0015] In this method, block copolymer self-assembly in the data zone 110 is guided with pre-patterned dots created with a template. The pre-patterned dots may create chemical/topographical contrast to anchor self-assembly location of polymer blocks and achieve the long range ordering for block copolymer assembly in the data zone.

[0016] In an embodiment, a method of self-assembling density multiplied block copolymers (BCP) structures in the data zone 110 includes coating a substrate with an imprint resist. A composition of the BCP is chosen to have a selected molecular weight and natural lattice constant L_0 , wherein the BCP composition includes a first polymer block (A) and a second polymer block (B). The resist is imprinted with an imprint template having imprint features in the data zone 110 spaced at a pitch distance L_s based on the selected composition of the BCP and satisfying the equation $L_s = n \times L_0$, where n is an integer density multiplication factor = 0, 1, 2, 3, etc. The imprint resist is cured, and additional process may be performed to prepare the substrate and imprint resist for coating with the BCP. The BCP is annealed to laterally segregate the BCP into self-assembled structures of the first polymer block A surrounded by the second polymer block B, the structures having a lateral spatial pitch of L_0 . Thus, the linear density of block A structures (e.g., pillars, spheres, and the like, depending on the choice of polymers) is n times the linear density of

the template features imprinted in the resist. In a template having hexagonal close-packed (hcp) arrangement of the imprinted features, the areal density of self-assembled block A structures is n^2 times that of the template.

[0017] In all embodiments described herein, annealing may be a thermal, chemical (including solvent), irradiative process, or the like.

[0018] In the servo zone **120**, BCP self-assembly is mainly guided by pre-defined line patterns provided by the template. By controlling a thickness of the BCP spin-coated over the line patterns, the BCP assembles in grooves between the line ridges. By pre-defining a shape and spacing of the lines, self-assembly of BCP may be confined to servo zone formation.

[0019] Disclosed herein is a system and processes for incorporating hybrid-guided growth of BCPs in the BPM manufacturing process. Specifically, the processes described herein illustrate how BCPs may be used to form hybrid nano-patterns on a bit pattern media (BPM) substrate. An imprint technique may be used to guide the growth of BCP structures. As a result, embodiments of this disclosure may avoid the pattern defects and chemo-toxicity associated with e-beam lithography techniques. One having ordinary skill in the art will appreciate that different BCPs may be used, such as a cylindrical, lamellar or spherical BCP. In an embodiment, the BCP may have organic components, inorganic components, or a combination of organic and inorganic components. BCP selection may be based upon the size, molecular weight, or other features of the BCP constituent units that are described further below. While specific BCPs are selected for the particular application, the process disclosed herein is a generalized process. Other variations are discussed further below and are illustrated in the figures.

[0020] In the following examples, the BCP is comprised of at least two constituent units, structural units or “blocks”, herein termed “block A” and “block B”, or “A block” and “B block”. The following examples describe removal of the A block; however, a person having ordinary skill in the art will appreciate that in an embodiment, the B block may be removed instead of the A block. Use of the singular “block A” or “block B” also includes use of plural “blocks A” and “blocks B.” As described above, block A and block B may be organic or inorganic, or block A may be organic, and block B inorganic, or block A may be inorganic and block B organic. In an embodiment, block A or block B comprises an organic polystyrene-block-polymethylmethacrylate (PS-b-PMMA), polystyrene-block-poly2-vinylpyridine, polystyrene-block-poly4-vinylpyridine, polystyrene-block-polyethyleneoxide, polystyrene-block-polyisoprene or polystyrene-block-butadiene. In an embodiment, block A or block B comprises an inorganic polystyrene-block-polydimethylsiloxane (PS-b-PDMS or, more compactly, PS-PDMS) or polystyrene-block-polyferrocenylsilane. A person having ordinary skill in the art will appreciate that the processes described herein may be varied accordingly depending upon the chemical characteristics of the BCP blocks. One will appreciate that selection of the BCP may also depend upon the target pattern to be created using the BCP. For example, the topographical pattern left by the imprinting described below may determine the selection of the BCP, since certain BCP blocks may correlate better with certain topographical pattern features and pattern dimensions. For example, PS-PDMS may be utilized to form spherical BCP structures.

[0021] In an aspect of the disclosure, FIGS. 3A-3F illustrates an example of a method **300** for integrated data zone **110** and servo zone **120** template fabrication, using PS-PDMS as a typical spherical BCP. Referring to FIGS. 3A and 3B, in an embodiment of the disclosure, a method **300** of self-assembling density multiplied block copolymers (BCP) structures in the data zone **110** and the servo zone **120** includes coating a substrate **315** with an imprint resist. A low resolution template produces pillars **310** in the data zone **110** of a first height and spacing, and lines **320** of a second height in the servo zone **120**. For reasons discussed below, the second height of the lines **320** is greater than the first height of the pillars **310**. A composition of the BCP is chosen to have a selected molecular weight and natural lattice constant L_0 , wherein the BCP composition includes a first polymer block (A) and a second polymer block (B). The resist is imprinted with an imprint template having imprinted pillars **310** spaced at a pitch distance L_s based on the selected composition of the BCP and satisfying the equation $L_s = n \times L_0$, where n is an integer density multiplication factor=0, 1, 2, 3, etc. The imprint resist is cured, and additional process steps may be performed to prepare the substrate and imprint resist for coating with the BCP. The BCP is annealed to laterally segregate the BCP into self-assembled structures of the first polymer block A surrounded by the second polymer block B, the structures having a lateral spatial pitch of L_0 . Thus, the linear density of block A structures (e.g., pillars, spheres, and the like, depending on the choice of polymers) is n times the linear density of the template features imprinted in the resist. In a template having hexagonal close-packed (hcp) arrangement of the imprinted features, the areal density is n^2 times that of the template.

[0022] In the servo zone **120**, BCP self-assembly is mainly guided by pre-defined lines **320** provided by the template. By controlling a thickness of the BCP coated over the lines **320**, the BCP is not able to self-segregate during annealing in the space over the lines **320**, but only assembles in grooves between the lines **320**. By pre-defining a shape and spacing of the lines, self-assembly of BCP will be confined to desired servo zone **120** formation.

[0023] FIG. 3A shows a cross-section, and FIG. 3B shows a plan view of an example structure of a hybrid self-assembly guiding pre-pattern: In the data zone **110**, pre-register pillars **310** are formed in resist at a spacing L_s patterned for BCP guided self-assembly in an hcp array with the lattice constant L_0 , determined by the choice of polymers A and B, on a substrate **315**. In the servo zone **120**, ridge lines **330** are applied to confine BCP self-assembly, where the spacing between the lines **320** are selected based on a similar rule, i.e., $L_s = n' \times L_0$, where the gap L_s is the gap space between the lines **320**, and is an integer multiple n' of the natural lattice constant L_0 of the selected BCP.

[0024] Referring to FIG. 3C, the BCP is annealed to induce lateral segregation of the A and B block polymers. In an aspect of the disclosure, the thickness of the deposited BCP is selected so that in the data zone **110**, the pillars **310** anchor the formation of spherical block A polymer dot (e.g., PDMS spheres) surrounded by block B polymer (e.g., polystyrene PS) with long-range ordering determined by the relationship $L_s = n \times L_0$. In the example shown in FIGS. 3A-3C, $n=2$, but L_s may be chosen for n having another integer value.

[0025] In the servo zone **120**, the height of the ridge lines **330** and the thickness of the BCP coating over the lines **320** may be chosen to be too thin to permit formation of block A

polymer on top of the lines **320**. Instead, lateral segregation of A and B polymers may be restricted to the space between the ridge lines **320** according to $L_s = n' \times L_0$, where n' is an integer density multiplication factor=0, 1, 2, 3, etc. In the example shown, $n'=2$, but the spacing may be larger to accommodate n' rows of block A polymer dots.

[0026] FIG. 3D illustrates the result removal of selective etch removal of the exposed B polymer block and imprint resist after annealing. The selective etch may be an O_2 reactive ion etch, for example, which does not substantially remove the A polymer block, which acts as an etch mask. After coating, and annealing, due to the topographical effect, formation of pillars comprising spherical block PDMS atop a columns of PS masked by the PDMS during the etch removal process resulting in long-range ordered pillar features **350** with high placement accuracy may be achieved in the data zone **110**. In the servo zone **120**, block copolymer on top of the ridge lines **320** may not self-assemble well due to copolymer thinness. Grooves force BCP to align to them and confine BCP into designed servo formation.

[0027] The remaining A polymer (e.g., spherical polymer) and B polymer and resist masked by the A polymer may serve as a mask. Referring to FIG. 3E, in an aspect of the disclosure, substrate **315** may be quartz, or a material suitable for etching in a process that does not also substantially etch the A and B polymers and resist. Thus, the substrate may be etched to produce a template **316** from the substrate, as shown in FIG. 3E, after removal of the A and B polymers and resist.

[0028] A plan view of the template **316** is shown in FIG. 3F, where the dots represent the pillars remaining after the substrate **316** has been etched and all polymers and resist removed. The resulting template may be used to imprint a resist or other imprintable material a substrate on which, for example, magnetic, magneto-optical, optical, electronic or equivalent high density features may be formed.

[0029] In another aspect of the disclosure, FIGS. 4A-4F illustrate another example for integrated template fabrication using hybrid guiding pre-pattern for BCP self-assembly with cylindrical block copolymer, such as PS-PMMA. FIG. 4A illustrate a side view of a substrate **415** having a resist imprinted with a low density template (not shown). The template may imprint features with different heights, as described below. In a data-zone **110**, low-density pre-registered pillar dots **410** of resist of a first height are formed for guided BCP self-assembly. In a servo zone **120**, BCP assembly will be confined by a combination of resist lines **420** and low density pre-registration resist pillar dots **425**. Ridges will define the shape of servo formation and long range order placement accuracy of BCP self-assembly is enhanced by pre-registered resist dots. Pre-registered pillar dots **410**, **425** and lines **420** may be either feature protruded (pillar-type) or feature recessed (hole-type). In the following drawing, pillars are applied to illustrate the example. The height of the pillar dots **410** and **425** are lower than the height of the lines **420** for the same reasons given above with respect to FIGS. 3A-3F. Where the imprinting process does not completely remove resist from the regions surrounding the pillars **410**, **425** and lines **420**, additional desmearing and cleaning steps, such as reactive oxygen ion etching, oxygen plasma ashing, or the like, may be used.

[0030] FIG. 4C illustrate block copolymer self-assembly on the hybrid pre-pattern shown in FIGS. 4A and 4B. The resist imprinted substrate **415** is then coated with BCP, such as PS-PMMA. After annealing, the BCP laterally segregates

into columns of PMMA polymer (block A) surrounded by PS (polystyrene), where the pillars **410** of resist anchor and enforce the long range order of the density multiplied columns. For the servo zone **120**, block copolymer on top of lines **420** may not self-assemble due to a small thickness of BCP above the lines **420** imposed by the greater height of the lines **420**. The grooves in the servo zone **120** between the lines **420**, however, urge BCP lateral segregation to self-align and assemble to the PMMA block.

[0031] As shown in FIG. 4D, removing the PMMA block (e.g., block A) by an appropriate etching or chemical process leaves high density holes **440** in PS (polystyrene) with long range ordering and high placement accuracy in the data zone **110** and high density holes **440** in PS (polystyrene) with long range ordering and high placement accuracy in the servo zone **120** due to the combination of the gap between lines **420** and pillar dots **425**. FIG. 4E is a plan view of the pattern of FIG. 4D.

[0032] In an aspect of the disclosure, the PS and lines **420** (of resist) coating the substrate **415** may be thinned by an appropriate removal technique (e.g., dry etching) to expose the substrate **415** beneath the holes **440**. The entire etched substrate **415**, including the remaining resist and PS, may be coated with a masking layer, such as Cr, and the remaining resist and PS removed, leaving Cr dots where PMMA columns previously stood. The substrate **415** may be an etch processible material like quartz, silicon, or the like, which can be etched with the Cr dots serving as a mask. The etching then forms a high density template, as shown in FIG. 4F, of pillars on the substrate including both the data zone **110** and the servo zone **120**, which may be used for imprint production of high density BPM.

[0033] As previously mentioned, the processes illustrated in FIGS. 3-4 and described herein may form part of a BMP media fabrication process. In an embodiment, this disclosure may be applied to any fabrication process featuring large-area high-density nano-patterning with long-range lateral ordering, such as patterning magnetic film layers in storage media, semiconductor production, and the like. In an embodiment, the processes described herein may be used to fabricate a template for use as a mask, thereby facilitating the deposition of functional materials or other additive processes. In an embodiment, the processes described herein may be used to facilitate the etching of functional materials, to directly or indirectly form a pattern on storage media, or other subtractive processes. Other applications are possible without departing from the scope of this disclosure.

[0034] The previous description is provided to enable any person skilled in the art to practice the various aspects described herein. Various modifications to these aspects will be readily apparent to those skilled in the art, and the generic principles defined herein may be applied to other aspects. Thus, the claims are not intended to be limited to the aspects shown herein, but is to be accorded the full scope consistent with the language of the claims, wherein reference to an element in the singular is not intended to mean "one and only one" unless specifically so stated, but rather "one or more." Unless specifically stated otherwise, the term "some" refers to one or more. A phrase referring to "at least one of" a list of items refers to any combination of those items, including single members. As an example, "at least one of: a, b, or c" is intended to cover: a; b; c; a and b; a and c; b and c; and a, b and c. All structural and functional equivalents to the elements of the various aspects described throughout this disclosure that

are known or later come to be known to those of ordinary skill in the art are expressly incorporated herein by reference and are intended to be encompassed by the claims. Moreover, nothing disclosed herein is intended to be dedicated to the public regardless of whether such disclosure is explicitly recited in the claims. No claim element is to be construed under the provisions of 35 U.S.C. §112, sixth paragraph, unless the element is expressly recited using the phrase “means for” or, in the case of a method claim, the element is recited using the phrase “step for.”

What is claimed is:

1. A method comprising:
imprinting features in a resist with an imprint mold to form one or more topographic surface patterns on the resulting imprinted resist;
depositing a block copolymer (“BCP”) material on the imprinted resist, wherein a molecular dimension L_0 of the BCP material correlates by an integer multiple to a spacing dimension of the one or more topographic surface pattern on the resulting imprinted resist;
annealing the deposited BCP; and
removing at least a portion of the annealed BCP to form a template having discrete domains is formed.
2. The method of claim 1, further comprising treating imprinted resist the imprinted resist to form a chemical surface pattern.
3. The method of claim 2, wherein the treating of the imprinted resist comprises exposing the imprinted resist to oxygen plasma.
4. The method of claim 1, further comprising transferring the imprinted resist onto the substrate.
5. The method of claim 1, wherein the imprinting of the resist comprises applying a UV imprinting process.

6. The method of claim 1, wherein the imprinting of the resist comprises applying a thermal imprinting process.

7. The method of claim 1, wherein the imprinting of the resist comprises applying an inking imprinting process.

8. The method of claim 1, wherein the BCP material is selected from the group consisting of polystyrene-block-polymethylmethacrylate (PS-b-PMMA), polystyrene-block-poly2-vinylpyridine, polystyrene-block-poly4-vinylpyridine, polystyrene-block-polyethyleneoxide, polystyrene-block-polyisoprene, polystyrene-block-butadiene, and mixtures thereof.

9. The method of claim 1, wherein the BCP material is selected from the group of BCP materials consisting of polystyrene-block-polydimethylsiloxane (PS-b-PDMS), polystyrene-block-polyferrocenylsilane, and mixtures thereof.

10. The method of claim 1, wherein the removing of at least a portion of the annealed BCP forms the template having pitch of 5-100 nm.

11. The method of claim 1, wherein the removing of at least a portion of the annealed BCP forms the template having a bit density of at least 1 Tdpsi.

12. The method of claim 1, wherein the removing of at least a portion of the annealed BCP forms the template having at least one of a long-ranged laterally ordered 1D array and a long-ranged laterally ordered 2D array.

13. The method of claim 1, wherein the one or more topographical surfaces comprises differing heights.

14. The method of claim 1, further comprising using the template to pattern a second resist.

15. The method of claim 1, further comprising using the template as a mask.

16. An apparatus manufactured by the method of claim 1.

* * * * *